# imall

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

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## 60 V, 4.0 A, Low V<sub>CE(sat)</sub> **PNP Transistor**

ON Semiconductor's e<sup>2</sup>PowerEdge family of low V<sub>CE(sat)</sub> transistors are miniature surface mount devices featuring ultra low saturation voltage (V<sub>CE(sat)</sub>) and high current gain capability. These are designed for use in low voltage, high speed switching applications where affordable efficient energy control is important.

Typical applications are DC-DC converters and power management in portable and battery powered products such as cellular and cordless phones, PDAs, computers, printers, digital cameras and MP3 players. Other applications are low voltage motor controls in mass storage products such as disc drives and tape drives. In the automotive industry they can be used in air bag deployment and in the instrument cluster. The high current gain allows e<sup>2</sup>PowerEdge devices to be driven directly from PMU's control outputs, and the Linear Gain (Beta) makes them ideal components in analog amplifiers.

#### Features

- NSV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable
- These Devices are Pb-Free, Halogen Free/BFR Free and are RoHS Compliant

### **MAXIMUM RATINGS** ( $T_A = 25^{\circ}C$ )

Rating	Symbol	Мах	Unit
Collector-Emitter Voltage	V <sub>CEO</sub>	-60	Vdc
Collector-Base Voltage	V <sub>CBO</sub>	-80	Vdc
Emitter-Base Voltage	V <sub>EBO</sub>	-7.0	Vdc
Collector Current – Continuous	۱ <sub>C</sub>	-2.0	А
Collector Current – Peak	I <sub>CM</sub>	-4.0	А

#### THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Total Device Dissipation $T_A = 25^{\circ}C$ Derate above $25^{\circ}C$	P <sub>D</sub> (Note 1)	460 3.7	mW mW/°C
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$ (Note 1)	270	°C/W
Total Device Dissipation T <sub>A</sub> = 25°C Derate above 25°C	P <sub>D</sub> (Note 2)	540 4.3	mW mW/°C
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$ (Note 2)	230	°C/W
Junction and Storage Temperature Range	T <sub>J</sub> , T <sub>stg</sub>	–55 to +150	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

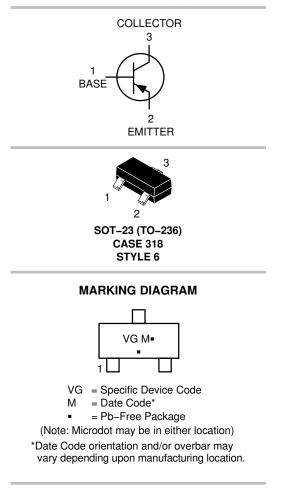
FR-4@100 mm<sup>2</sup>, 1 oz. copper traces.
FR-4@500 mm<sup>2</sup>, 1 oz. copper traces.



## **ON Semiconductor®**

#### www.onsemi.com

## -60 VOLTS, 4.0 AMPS $\begin{array}{c} \text{PNP LOW V}_{\text{CE(sat)}} \text{ TRANSISTOR} \\ \text{EQUIVALENT R}_{\text{DS(on)}} 80 \text{ m}\Omega \end{array}$



#### ORDERING INFORMATION

Device	Package	Shipping <sup>†</sup>
NSS60200LT1G	SOT-23 (Pb-Free)	3000/Tape & Reel
NSV60200LT1G	SOT-23 (Pb-Free)	3000/Tape & Reel

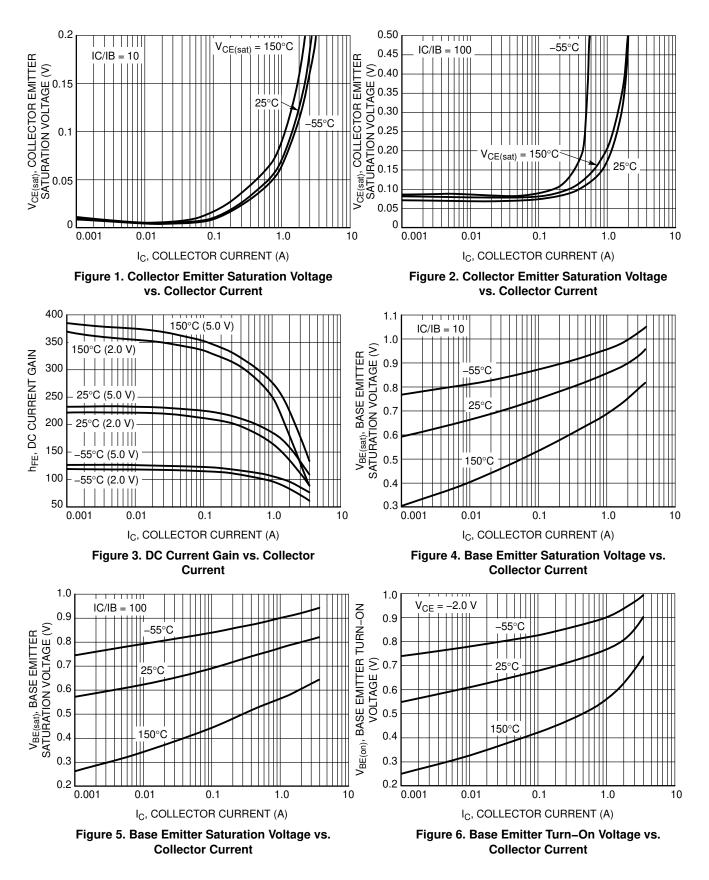
+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

### **ELECTRICAL CHARACTERISTICS** ( $T_A = 25^{\circ}C$ unless otherwise noted)

Characteristic	Symbol	Min	Тур	Max	Unit
OFF CHARACTERISTICS					
Collector – Emitter Breakdown Voltage $(I_C = -10 \text{ mAdc}, I_B = 0)$	V <sub>(BR)CEO</sub>	-60	_	_	Vdc
Collector – Base Breakdown Voltage $(I_C = -0.1 \text{ mAdc}, I_E = 0)$	V <sub>(BR)CBO</sub>	-80	-	_	Vdc
Emitter – Base Breakdown Voltage $(I_E = -0.1 \text{ mAdc}, I_C = 0)$	V <sub>(BR)EBO</sub>	-7.0	-	_	Vdc
Collector Cutoff Current ( $V_{CB} = -60 \text{ Vdc}, I_E = 0$ )	I <sub>CBO</sub>	-	-	-0.1	μAdc
Emitter Cutoff Current (V <sub>EB</sub> = -6.0 Vdc)	I <sub>EBO</sub>	_	-	-0.1	μAdc
ON CHARACTERISTICS					
$ \begin{array}{l} \text{DC Current Gain (Note 3)} \\ (I_{C} = -10 \text{ mA}, \text{ V}_{CE} = -2.0 \text{ V}) \\ (I_{C} = -500 \text{ mA}, \text{ V}_{CE} = -2.0 \text{ V}) \\ (I_{C} = -1.0 \text{ A}, \text{ V}_{CE} = -2.0 \text{ V}) \\ (I_{C} = -2.0 \text{ A}, \text{ V}_{CE} = -2.0 \text{ V}) \end{array} $	h <sub>FE</sub>	150 150 100 100	- 300 - -	- - - -	
	V <sub>CE(sat)</sub>	- - - -	-0.017 -0.095 -0.180 -0.170	-0.030 -0.120 -0.270 -0.220	V
Base – Emitter Saturation Voltage (Note 3) ( $I_C = -1.0 \text{ A}, I_B = -0.010 \text{ A}$ )	V <sub>BE(sat)</sub>	-	_	-0.900	V
Base – Emitter Turn–on Voltage (Note 3) ( $I_C = -1.0 \text{ A}, V_{CE} = -2.0 \text{ V}$ )	V <sub>BE(on)</sub>	-	_	-0.850	V
Cutoff Frequency (I <sub>C</sub> = $-100$ mA, V <sub>CE</sub> = $-5.0$ V, f = $100$ MHz)	f <sub>T</sub>	100	-	_	MHz
Input Capacitance (V <sub>EB</sub> = 0.5 V, f = 1.0 MHz)	Cibo	-	-	325	pF
Output Capacitance ( $V_{CB}$ = 3.0 V, f = 1.0 MHz)	Cobo	-	-	62	pF
SWITCHING CHARACTERISTICS					
Delay (V <sub>CC</sub> = $-30$ V, I <sub>C</sub> = 750 mA, I <sub>B1</sub> = 15 mA)	t <sub>d</sub>	_	-	60	ns
Rise (V <sub>CC</sub> = $-30$ V, I <sub>C</sub> = 750 mA, I <sub>B1</sub> = 15 mA)	t <sub>r</sub>	-	-	120	ns
Storage (V <sub>CC</sub> = -30 V, I <sub>C</sub> = 750 mA, I <sub>B1</sub> = 15 mA)	t <sub>s</sub>	-	-	400	ns
Fall (V <sub>CC</sub> = -30 V, I <sub>C</sub> = 750 mA, I <sub>B1</sub> = 15 mA)	t <sub>f</sub>	_	-	130	ns

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions. 3. Pulsed Condition: Pulse Width = 300 msec, Duty Cycle  $\leq 2\%$ .

## **TYPICAL CHARACTERISTICS**



## **TYPICAL CHARACTERISTICS**

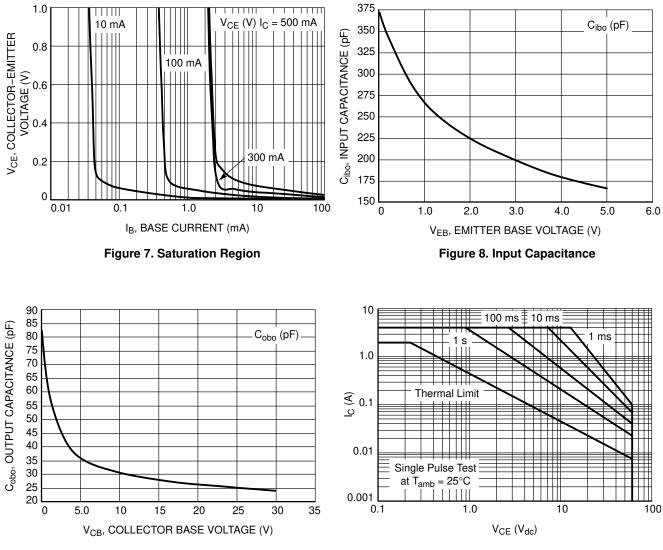
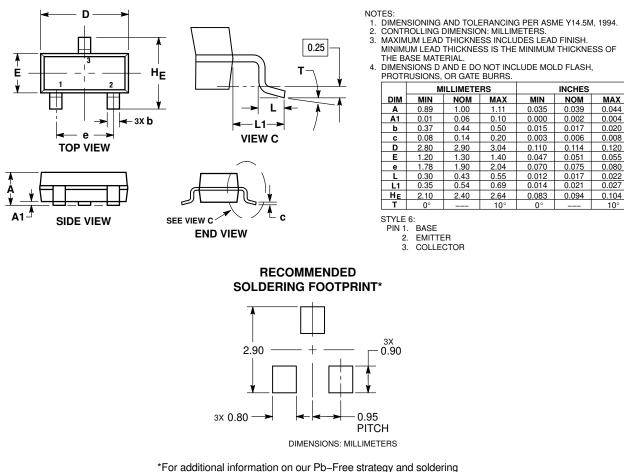


Figure 9. Output Capacitance

Figure 10. Safe Operating Area

#### PACKAGE DIMENSIONS

SOT-23 (TO-236) CASE 318-08 ISSUE AR



\*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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